

Paper Code: EC-401

Roll No.

--	--	--	--	--	--	--	--	--	--

B.Tech.
(SEM IV) EVEN SEMESTER EXAMINATION, 2015-16
ELECTRONIC CIRCUITS

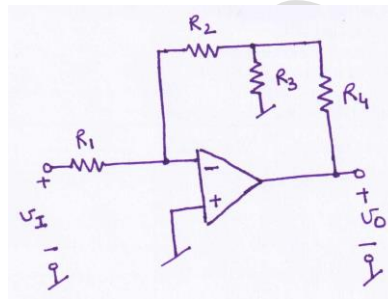
[Time: 3 hrs.]

[Max. Marks: 100]

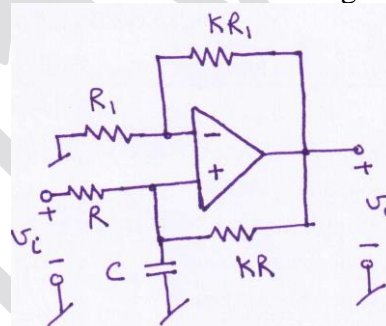
Note- Attempt All Questions. All Questions carry equal marks.

1. Attempt any **four** parts of the following: [5x4=20]

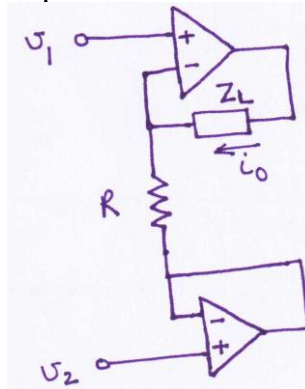
- (a) Using op-amp draw the practical circuits of VCVS and CCVS. Justify your answer.
- (b) Describe how the performance of an op-amp is affected by the finite open loop gain of amplifier.
- (c) Assume the op-amp to be ideal, derive an expression for the close-loop gain v_o/v_i of the circuit shown in figure.



(d) What is the transfer function for the circuit shown in figure?



(e) The circuit in figure represents a current source that forces a current through the floating load impedance Z_L . Find the relationship between the current i_o and the input voltage v_1 and v_2 .



(f) Draw the circuit diagram three op-amp instrumentation amplifier and drive the expression for the output voltage.

2. Attempt any **two** parts of the following: [10x2=20]
- (a) MOSFET as an amplifier. Justify your answer using mathematical model.
- (b) Explain channel length modulation and derive an expression for drain current influence of channel length modulation.
- (c) Consider a common-source amplifier with source resistance and find the expression for the amplifier input resistance, overall voltage gain, output resistance, short circuit current gain.
3. Attempt any **two** parts of the following: [10x2=20]
- (a) Discuss briefly the charge transport model in a BJT and show that in saturation condition the $\beta_{forced} < \beta_F$.
- (b) Consider a common-base amplifier and find the expression for the amplifier input resistance, output voltage, voltage gain, open circuit voltage gain, overall voltage gain, output resistance, short circuit current gain.
- (c) Discuss the various internal capacitances in detail for BJT. Draw the high frequency hybrid- π model of bipolar junction transistor. Drive the expression for the unit gain bandwidth is given as:
- $$f_T = \frac{g_m}{2\pi(C_\pi + C_\mu)}$$
4. Attempt any **two** parts of the following: [10x2=20]
- (a) Write the features of differential amplifier. Draw the circuit of MOS differential pair configuration and describe its common mode operation for the determination of over drive voltage.
- (b) Drive the expression for differential gain of the MOS differential amplifier with differential input.
- (c) Explain the small-signal operation of the BJT differential amplifier and show that the differential input resistance R_{id} is given as:
- $$R_{id} = (\beta + 1)(2r_e + 2R_E)$$
5. Attempt any **two** parts of the following: [10x2=20]
- (a) Explain the working of a Wien Bridge oscillator. Derive an expression for the frequency of oscillations. What are the merits and demerits of such oscillator?
- (b) Merits and demerits of negative feedback. Explain four basic feedback topologies.
- (c) Write a short notes on any **two** of the following:
- i. Slew rate and full power bandwidth.
 - ii. Early effect and Early voltage
 - iii. LC oscillators